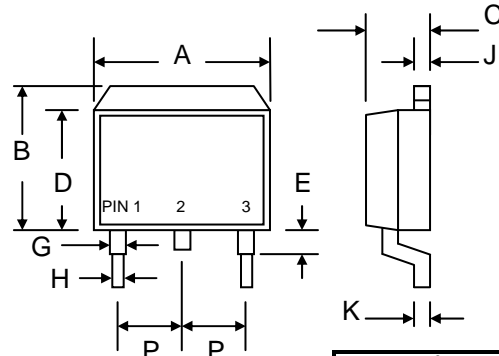


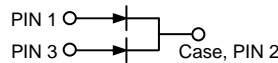
## Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Super-Fast Recovery Time
- High Voltage Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in High Voltage, High Frequency Inverters, Free Wheeling, and Switching Power Supplies



## Mechanical Data

- Case: D<sup>2</sup>PAK/TO-263, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 1.7 grams (approx.)
- Mounting Position: Any
- Marking: Device Code, See Page 3
- **Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4**



D <sup>2</sup> PAK/TO-263		
Dim	Min	Max
A	9.80	10.40
B	9.60	10.60
C	4.40	4.80
D	8.50	9.10
E	—	2.80
G	1.00	1.40
H	—	0.99
J	1.20	1.40
K	0.30	0.70
P	2.35	2.75
All Dimensions in mm		

## Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MURHB 820CT	MURHB 830CT	MURHB 840CT	MURHB 860CT	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>					
Working Peak Reverse Voltage	V <sub>RWM</sub>	200	300	400	600	V
DC Blocking Voltage	V <sub>R</sub>					
RMS Reverse Voltage	V <sub>R(RMS)</sub>	140	210	280	420	V
Average Rectified Output Current @T <sub>C</sub> = 100°C	I <sub>O</sub>			8.0 4.0		A
Total Device Per Diode						
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>		125			A
Forward Voltage per diode @I <sub>F</sub> = 4.0A	V <sub>FM</sub>	0.95	1.3	1.7		V
Peak Reverse Current At Rated DC Blocking Voltage	I <sub>RM</sub>			10 500		μA
@T <sub>C</sub> = 25°C @T <sub>C</sub> = 100°C						
Reverse Recovery Time (Note 1)	t <sub>rr</sub>	35		50		nS
Typical Junction Capacitance (Note 2)	C <sub>J</sub>	85		50		pF
Thermal Resistance Junction to Ambient per diode	R <sub>JA</sub>			60		°C/W
Thermal Resistance Junction to Case per diode	R <sub>JC</sub>			3.0		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>			-55 to +150		°C

Note: 1. Measured with I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>RR</sub> = 0.25A.  
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

# MURHB820CT – MURHB860CT

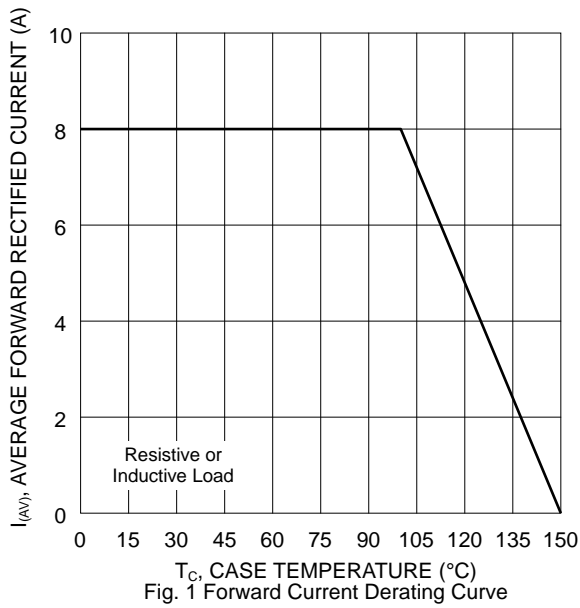


Fig. 1 Forward Current Derating Curve

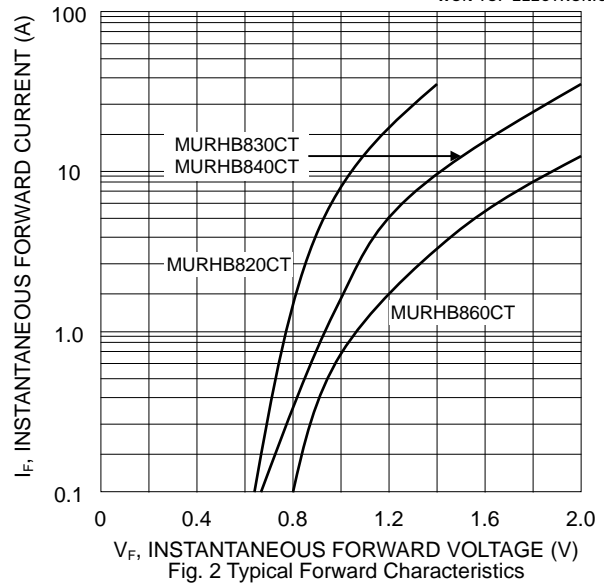


Fig. 2 Typical Forward Characteristics

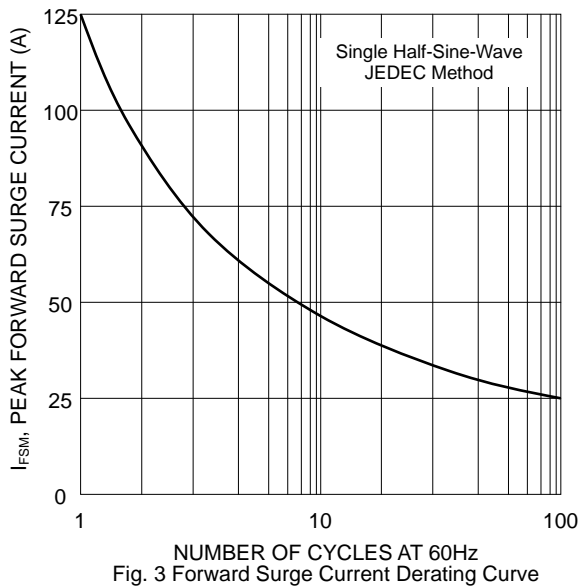


Fig. 3 Forward Surge Current Derating Curve

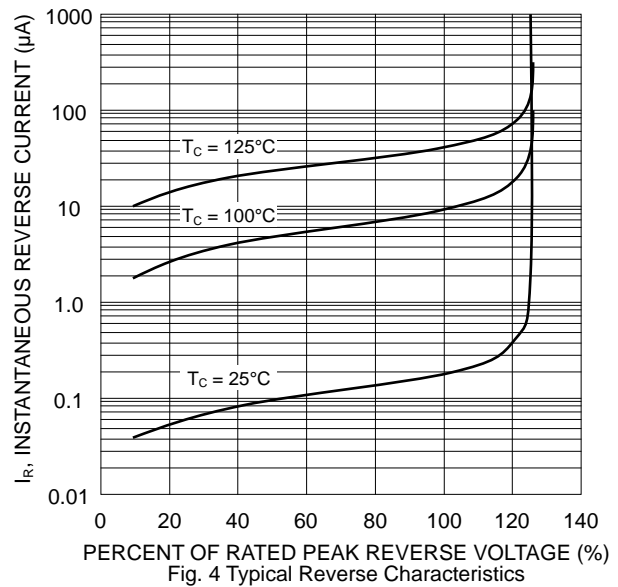


Fig. 4 Typical Reverse Characteristics

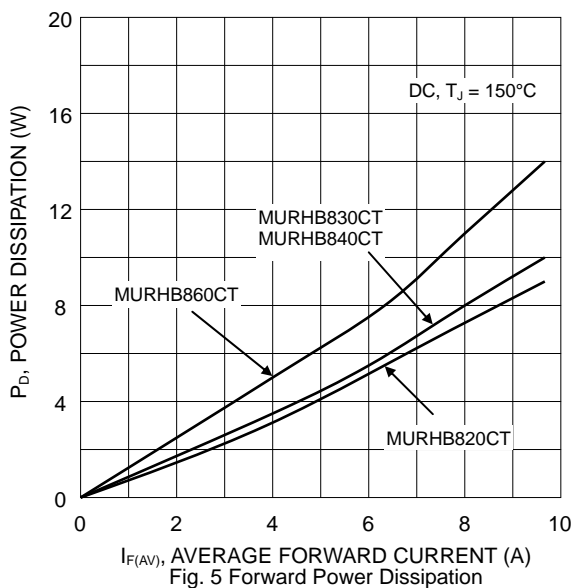


Fig. 5 Forward Power Dissipation

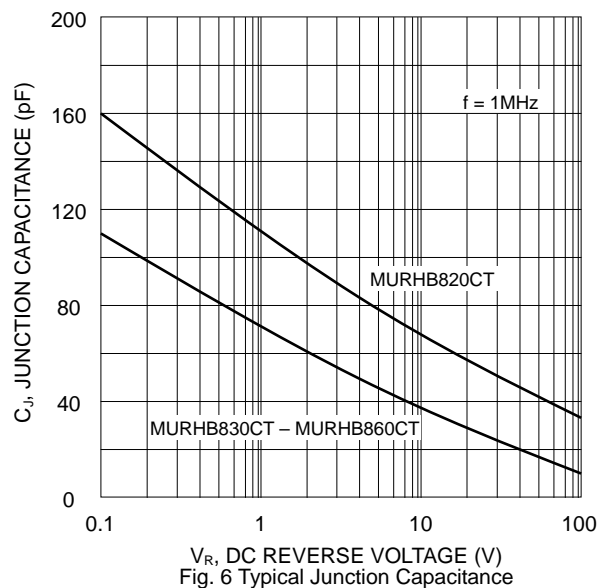
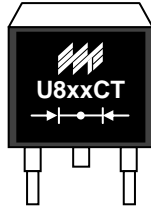


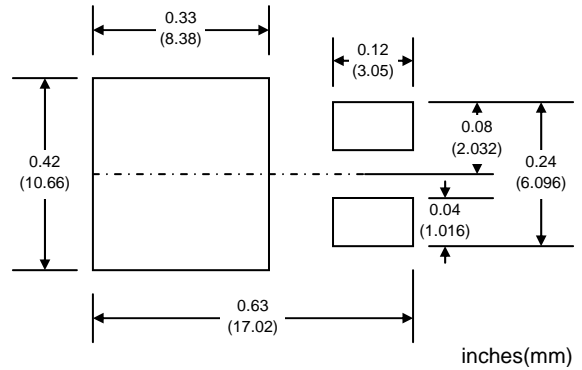
Fig. 6 Typical Junction Capacitance

## MARKING INFORMATION



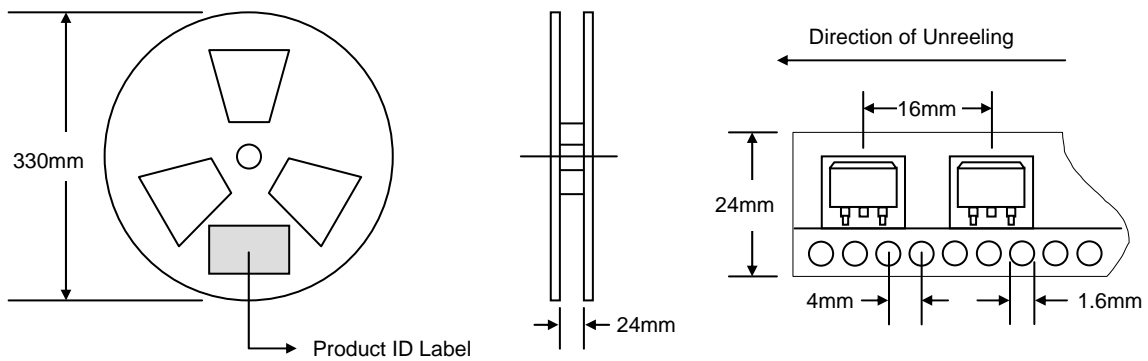
U8xxCT = Device Number  
 xx = 20 (MURHB820CT)  
       30 (MURHB830CT)  
       40 (MURHB840CT)  
       60 (MURHB860CT)  
 Polarity = As Marked on Body

## RECOMMENDED FOOTPRINT



## PACKAGING INFORMATION

### TAPE & REEL



Reel Diameter (mm)	Quantity (PCS)	Inner Box Size L x W x H (mm)	Quantity (PCS)	Carton Size L x W x H (mm)	Quantity (PCS)	Approx. Gross Weight (KG)
330	800	340 x 337 x 45	800	370 x 370 x 420	6,400	15.0

**Note:** 1. Paper reel, white or gray color.  
 2. Components are packed in accordance with EIA standard 481-1 and 481-2.

## ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
MURHB820CT-T3	D <sup>2</sup> PAK	800/Tape & Reel
MURHB830CT-T3	D <sup>2</sup> PAK	800/Tape & Reel
MURHB840CT-T3	D <sup>2</sup> PAK	800/Tape & Reel
MURHB860CT-T3	D <sup>2</sup> PAK	800/Tape & Reel

1. Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
2. **To order RoHS / Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, MURHB820CT-T3-LF.**

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**WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT.** WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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**Email:** sales@wontop.com  
**Internet:** <http://www.wontop.com>

*We power your everyday.*